Wei Zhao

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EDUCATION

Huazhong University of Science of Technology

Wuhan, Hubei province

B.E. in Electrical Science and Technology
School of Optical and Electrical Information (OEI)

Sep 2014 - Jun 2018

Huazhong University of Science of Technology

Wuhan, Hubei province

Ph.D. in Computer Architecture

Sep 2018 - Jun 2023

Wuhan National Laboratory for Optoelectronics (WNLO)

- o Supervisor: Dan Feng
- o Research Areas in my Ph.D. career:

Non-volatile Memory (NVM), Computing-in Memory, Memory and Storage System.

PUBLICATIONS

Conference Papers

- Heng Zhou, Bing Wu, Huan Cheng, <u>Wei Zhao</u>, Xueliang Wei, Jinpeng Liu, Dan Feng and Wei Tong, "ODLPIM: A Write-Optimized and Long-Lifetime ReRAM-Based Accelerator for Online Deep Learning", in proceedings of 26th Design, Automation and Test in Europe Conference (DATE'23, CCF B).
- 2. Denghui Wu, Biyong Liu, <u>Wei Zhao</u>, Wei Tong. "ZNSKV: Reducing Data Migration in LSMT-Based KV Stores on ZNS SSDs" is accepted by 40th IEEE International Conference on Computer Design (ICCD'22, CCF B).
- 3. <u>Wei Zhao</u>, Dan Feng, Yu Hua, Wei Tong, Jingning Liu, Jie Xu, Chunyan Li, Gaoxiang Xu and Yiran Chen. "MORE²: Morphable Encryption and Encoding for Secure NVM", in Proceedings of 40-th International Conference On Computer-Aided Design (ICCAD'21, CCF B).
- 4. <u>Wei Zhao</u>, Wei Tong, Dan Feng, Jingning Liu, Zhangyu Chen, Jie Xu, Bing Wu, Chengning Wang and Bo Liu. "Improving the energy efficiency of STT-MRAM based approximate cache", in Proceedings of 24-th Design, Automation and Test in Europe Conference (DATE'21, CCF B).
- 5. <u>Wei Zhao</u>, Wei Tong, Dan Feng, Jingning Liu, Jie Xu, Xueliang Wei, Bing Wu, Chengning Wang, Weilin Zhu, Bo Liu. "OSwrite: Improving the lifetime of MLC STT-RAM with One-Step write", in proceedings of 36-th International Conference on Massive Storage Systems and Technology (MSST'20, CCF B).
- 6. Bing Wu, Dan Feng, Wei Tong, Jingning Liu, Chengning Wang, Wei Zhao, Mengye Peng.

"ReRAM Crossbar-Based Analog Computing Architecture for Naive Bayesian Engine", in Proceedings of International Conference of Computer Design (ICCD'19, CCF B).

Journal Papers

- 1. Dong Huang, Dan Feng, Qiankun Liu, Bo Ding, <u>Wei Zhao</u>, Xueliang Wei, Wei Tong. "SplitZNS: Towards an Efficient LSM-Tree on Zoned Namespace SSDs" is accepted by ACM Transactions on Architecture and Code Optimization (TACO, CCF A), 2023.
- 2. <u>Wei Zhao</u>, Dan Feng, Wei Tong, Jingning Liu, Zhangyu Chen, Bing Wu, Chengning Wang. "APPcache+: An STT-MRAM based Approximate Cache System with Low Power and Long Lifetime" is accepted by Transactions on Computer-Aided Design of Integrated Circuits and Systems (TCAD, CCF A), 2023.
- 3. <u>Wei Zhao</u>, Jie Xu, Xueliang Wei, Bing Wu, Chengning Wang, Weilin Zhu, Wei Tong, Dan Feng, Jingning Liu. "A Low Latency and High Endurance MLC STT-MRAM based Cache System" in Transactions on Computer-Aided Design of Integrated Circuits and Systems (TCAD, CCF A), 2022.
- 4. Chengning Wang, Dan Feng, Wei Tong, Yu Hua, Jingning Liu, Bing Wu, <u>Wei Zhao</u>, Linghao Song, Yang Zhang, Jie Xu, Xueliang Wei, Yiran Chen. "Improving Multilevel Writes on Vertical 3D Cross-Point Resistive Memory", accepted by Transactions on Computer-Aided Design of Integrated Circuits and Systems (TCAD, CCF A), 2020.
- Chengning Wang, Dan Feng, Wei Tong, Jingning Liu, Bing Wu, <u>Wei Zhao</u>, Yang Zhang, Yiran Chen. "Improving Write Performance on Cross-Point RRAM Arrays by Leveraging Multidimensional Non-Uniformity of Cell Effective Voltage", accepted by Transactions on Computers (TC, CCF A), 2020.
- 6. Chengning Wang, Dan Feng, Wei Tong, Jingning Liu, Bing Wu, Wei Zhao, Yang Zhang. "Design and Analysis of Address-Adaptive Read Reference Settings for Multilevel Cell Cross-Point Memory Arrays", accepted by IEEE Transactions on Electron Devices (TED), 2019.
- 7. Bing Wu, Dan Feng, Wei Tong, Jingning Liu, Chengning Wang, <u>Wei Zhao</u>, Yang Zhang. "A low power reconfigurable memory architecture for complementary resistive switches", accepted by IEEE Transactions on Computer-Aided Design of Integrated Circuits and Systems (TCAD, CCF A), 2019.
- 8. Chengning Wang, Dan Feng, Wei Tong, Jingning Liu, Zheng Li, Jiayi Chang, Yang Zhang, Bing Wu, Jie Xu, <u>Wei Zhao</u>, Yilin Li, Ruoxi Ren, "Cross-point resistive memory: Nonideal properties and solutions", ACM Transactions on Design Automation of Electronic Systems (TODAES, CCF B), 2019.

TALKS

- "MORE2: Morphable Encryption and Encoding for Secure NVM", oral presentation in ICCAD 2021.
- o "Improving the energy efficiency of STT-MRAM based approximate cache", oral presentation in

DATE 2021.

 "OSwrite: Improving the lifetime of MLC STT-RAM with One-Step write", oral presentation in MSST 2020.

Patents

- 1. 一种通过数据模式重布局降低 MLC NAND 闪存误码率的方法 [发明,已授权], 童薇,刘景宁,冯 丹,赵雨桐,覃鸿巍,**赵威**,申请号: CN201811506261.5
- 2. 一种适用于 MLC NAND 闪存的 LDPC 码译码方法 [发明,已授权], 童薇,刘景宁,冯丹,赵雨桐,覃鸿巍,**赵威**,申请号: CN201811401607.5
- 3. 一种提升 STT-MRAM 近似缓存能效的方法及系统 [发明,已授权],童薇,冯丹,<u>赵威</u>,陈章玉,吴兵,汪承宁,申请号: CN202110484855.6
- 4. 基于阻变存储阵列的朴素贝叶斯分类方法、引擎及系统 [发明,已授权],冯丹,童薇,彭梦烨,吴 兵,赵威,申请号: CN201911100579.8

Industry Standards

- 1. 信息技术 存储管理 第 2 部分: 通用架构,标准号: GB/T 36450.2-2021
- 2. 信息技术 存储管理 第 5 部分: 文件系统,标准号: GB/T 36450.5-2021
- 3. 信息技术 存储管理 第 6 部分: 交换结构,标准号: GB/T 36450.6-2021
- 4. 信息技术 存储管理 第7部分: 主机元素,标准号: GB/T 36450.7-2021
- 5. 信息技术 存储管理 第 8 部分: 媒体库,标准号: GB/T 36450.8-2021

SKILLS

- o Programming Language C, C++, Python, Shell, CUDA
- o Tools − Git, IAT_EX
- Simulators Gem5, NVmain, GPGPUsim. NVsim.
- Language Good English Writing, Reading.

AWARDS

- o Outstanding undergraduate graduate of HUST in 2018.
- Excellent Postgraduate Student in HUST, 2019.
- o ZhiXing Excellent Postgraduate Scholarship (1000 CNY), 2020.
- o WNLO Excellent Postgraduate Scholarship (10000 CNY), 2021

Academic Services

o The reviewer of International Journal of Information Technology & Decision Making (JCR Q3).

- $\circ\,$ The reviewer of DAC 2023 (CCF A).
- $\circ\,$ The reviewer of ICIC 2023 (CCF C).
- \circ The sub-reviewer of ATC 2023 (CCF A).
- ${\color{blue} \circ}$ The sub-reviewer of FAST 2023 (CCF A).